SCS206AGHR

Automotive Grade SiC Schottky Barrier Diode

Datasheet

V_R	650V
I _F	6A
Q _C	9nC

Outline TO-220AC (1) (2) (3)

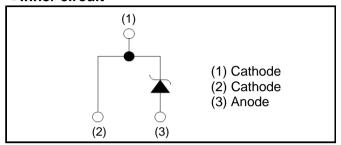
Features

- 1) AEC-Q101 qualified
- 2) Low forward voltage
- 3) Negligible recovery time/current
- 4) Temperature independent switching behavior

Applications

- · On Board Charger
- DC/DC Converter
- · Wireless Charger
- EV Charger

•Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS206AG

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V _R	650	V
Continuous forward	current (T _c = 138°C)	I _F	6	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		23	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C I _{FSM}		18	А
current	PW=10μs square, T _j =25°C		90	А
Repetitive peak forward current		I _{FRM}	27 ^{*1}	А
PW=10ms, T _j =25°C		$\int i^2 dt$	2.6	A ² s
i ² t value	PW=10ms, T _j =150°C	J i⁻dt	1.6	A ² s
Total power dissipation		P_D	51 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =1.2mA	650	-	-	V
	V _F	I _F =6A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =6A,T _j =150°C	-	1.55	-	V
		I _F =6A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	1.2	120	μΑ
		V _R =600V,T _j =150°C	-	18	-	μΑ
		V _R =600V,T _j =175°C	-	42	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	220	-	pF
		V _R =600V,f=1MHz	-	22	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	9	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	ı	12	-	ns

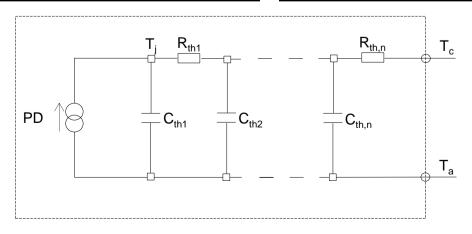
Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	ı	2.6	2.9	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	1.00E+00	
R _{th2}	1.28E+00	K/W
R _{th3}	2.70E-01	

Symbol	Value	Unit
C_{th1}	1.13E-03	
C_{th2}	3.44E-03	Ws/K
C_{th3}	3.11E-01	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

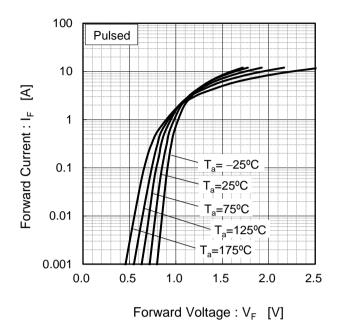
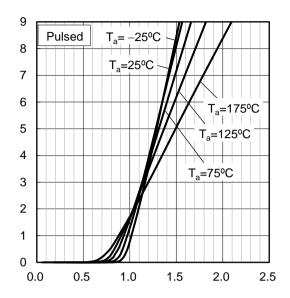


Fig.2 V_F - I_F Characteristics

Forward Current : IF [A]



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

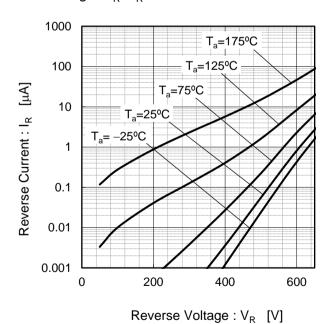
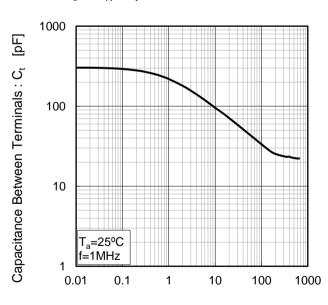


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

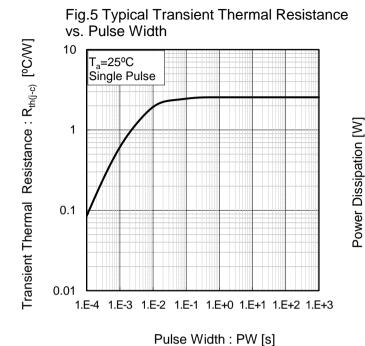


Fig.6 Power Dissipation 60 50 40 30 20 10 175 25 50 75 100 125 150

Case Temperature : T_c [°C]

Datasheet

Fig.7*3 Maximum peak forward current derating curve I_P - T_c 70 60 Peak Forward Current: Ip [A] 50 Duty=0.1 40 Duty=0.2 30 Duty=0.5 20 10 Duty=0.8 D.C 0 25 50 75 100 125 150 175 Case Temperature : T_c [°C]

*3 Based on max Vf, max R_{th(j-c)}

excluding D.C. curve.

Valid for switching of above 10kHz,

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed) 70 60 Duty=0.1 50 Duty=0.2 40 30 Duty=0.5 20 10 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

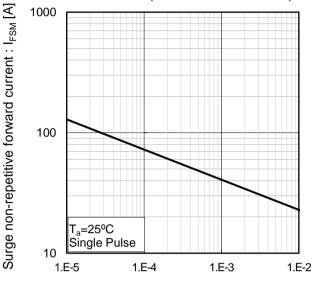
Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : IP [A]

SCS206AGHR

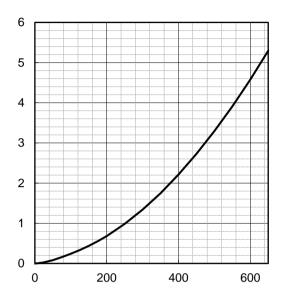
Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

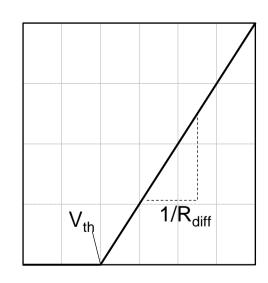
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	6.63E-02	Ω
b ₁	1.70E-04	Ω/°C
b ₂	1.80E-06	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 12 A

Forward Current: IF

Capacitance stored energy ։ $\mathsf{E}_\mathsf{C}[\mu J]$

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